Docket No.: 60188-431

**PATENT** 

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Application of

Akihiko ISHIBASHI, et al.

Serial No.: 10/017,389

Group Art Unit: 2818

Filed: December 18, 2001

Examiner: TRAN, MAI HUONG C.

For:

METHOD FOR FABRICATING SEMICONDUCTOR, METHOD FOR FABRICATING

SEMICONDUCTOR SUBSTRATE, AND SEMICONDUCTOR LIGHT EMITTING

**DEVICE** 

## PETITION FOR EXTENSION OF TIME

Mail Stop Extension of Time Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

It is respectfully requested that the time for response to the Office Action dated March 20, 2003, now due to expire April 20, 2003, be extended for two month(s) and set to expire on June 20, 2003.

Please charge the extension fee of \$410.00 to Deposit Account No. 500417. Please charge any additional fees or credit any overpayment to Deposit Account No. 500417.

Respectfully submitted,

MCDERMOTT, WILL & EMERY

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Date: June 20, 2003